

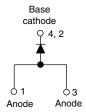
Vishay Semiconductors

HALOGEN

FREE

Schottky Rectifier, 10 A





20 mJ

E_{AS}

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	10 A			
V_{R}	45 V			
V _F at I _F	0.53 V			
I _{RM}	15 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-10WQ045FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	10	Α		
V_{RRM}		45	V		
I _{FSM}	t _p = 5 μs sine	400	Α		
V _F	10 A _{pk} , T _J = 125 °C	0.53	V		
TJ	Range	- 40 to 175	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10WQ045FNHM3	UNITS
Maximum DC reverse voltage	V_{R}	45	V
Maximum working peak reverse voltage	V _{RWM}	45	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 157 °C	, rectangular waveform	10	Α
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	400	Α
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	75	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 4.4 \text{mH}$		mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 3.0		А	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{EM} ⁽¹⁾	10 A	T _J = 25 °C	0.63	V
Maximum forward voltage drop		20 A		0.80	
See fig. 1	VFM (*)	10 A	T _{.1} = 125 °C	0.53	
		20 A	1 J = 125 C	0.71	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Botod V-	1	mA
See fig. 2	IRM \ /	$V_R = Rated V_R$		15	
Threshold voltage	V _{F(TO)}	T _{.I} = T _{.I} maximum		0.255	V
Forward slope resistance	r _t			22	mΩ
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		760	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0		nH	

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		50	C/VV
Approximate weight			0.3	g
Approximate weight			0.01	oz.
Marking device		Case style D-PAK	10WQ0	45FNH

Note

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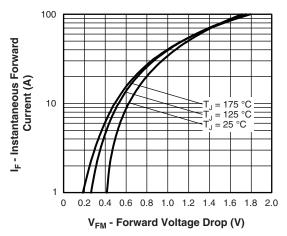


Fig. 1 - Maximum Forward Voltage Drop Characteristics

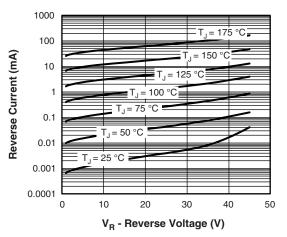


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

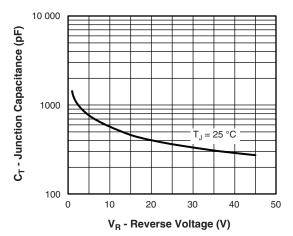


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

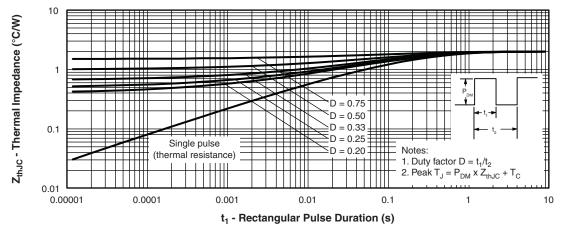


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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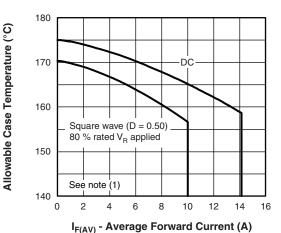


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

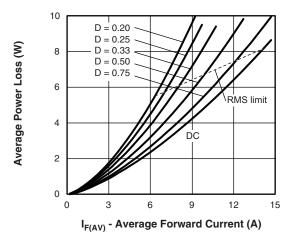


Fig. 6 - Forward Power Loss Characteristics

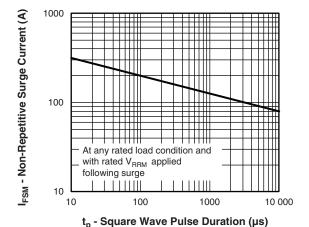


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

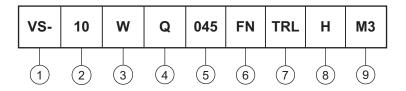
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (10 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (045 = 45 V)

- FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R MINIMUM ORDER QUANTITY		PACKAGING DESCRIPTION	
VS-10WQ045FNHM3	75	3000	Antistatic plastic tube	
VS-10WQ045FNTRHM3	2000	2000	13" diameter reel	
VS-10WQ045FNTRRHM3	3000	3000	13" diameter reel	
VS-10WQ045FNTRLHM3	3000	3000	13" diameter reel	

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95519</u>			
Part marking information www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033		



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